

STD888T4

Medium Current, High Performance, Low Voltage PNP Transistor

General features

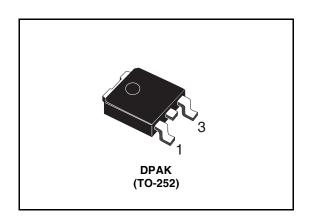
- Very low Collector to Emitter saturation voltage
- D.C. Current gain, h_{FE} >100
- 5A continuous collector current
- Surface mounting DPAK(TO-252) power package in tape & reel packing
- In compliance with the 2002/93/EC European Directive



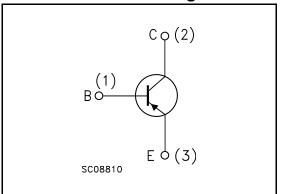
The device in manufactured in low voltage PNP Planar Technology by using a "Base Island" layout. The resulting transistor shows exceptional high gain performance coupled with very low saturation voltage.

Applications

- Power management in portable equipment
- Voltage regulation in bias supply circuits
- Switching regulator in battery charger applications
- Heavy load driver



Internal schematic diagram



Order codes

| Part Number | Marking | Package | Packing | |
|-------------|---------|---------|-------------|--|
| STD888T4 | D888 | DPAK | Tape & reel | |

April 2006 Rev 2 1/10

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STD888T4 Electrical ratings

1 Electrical ratings

Table 1. Absolute maximum rating

| Symbol | Parameter | Value | Unit |
|------------------|--|------------|------|
| V _{CBO} | Collector-base voltage (I _E = 0) | -45 | V |
| V _{CEO} | Collector-emitter voltage (I _B = 0) | -30 | V |
| V _{EBO} | Emitter-base voltage (I _C = 0) | -6 | V |
| I _C | Collector current | -5 | Α |
| I _{CM} | Collector peak current (t _P < 5ms) | -10 | Α |
| P _{tot} | Total dissipation at T _c = 25°C | 15 | W |
| T _{stg} | Storage temperature | -65 to 150 | °C |
| T _J | Max. operating junction temperature | 150 | °C |

Table 2. Thermal data

| Symbol | Parameter | Value | Unit |
|-----------------------|--------------------------------------|-------|------|
| R _{thj-case} | Thermal resistance junction-case max | 8.33 | °C/W |

Electrical characteristics STD888T4

2 Electrical characteristics

 $(T_{case} = 25^{\circ}C \text{ unless otherwise specified})$

Table 3. Electrical characteristics

| Symbol | Parameter | Parameter Test Conditions | | | | Unit |
|--|---|---|------------------|--------------------------------------|--------------------------|--------------------------|
| I _{CBO} | Collector cut-off current (I _E =0) | $V_{CB} = -30V$ $V_{CB} = -30V$; $T_{C} = 100^{\circ}C$ | | | -10 100 | μ Α μ Α |
| I _{EBO} | Emitter cut-off current (I _C =0) | V _{EB} = -6V | | | -10 | μА |
| V _{(BR)CEO} (2) | Collector-emitter breakdown voltage (I _B =0) | I _C = -10mA | -30 | | | V |
| V _{(BR)CBO} | Collector-base breakdown voltage (I _E =0) | I _C = -100μA | -45 | | | V |
| V _{(BR)EBO} | Emitter-base breakdown voltage (I _C =0) | I _E = -100μA | -6 | | | V |
| V _{CE(sat)} (2) | Collector-emitter saturation voltage | $\begin{split} & I_{C} = -0.5A & I_{B} = -5mA \\ & I_{C} = -2A & I_{B} = -50mA \\ & I_{C} = -5A & I_{B} = -250mA \\ & I_{C} = -6A & I_{B} = -250mA \\ & I_{C} = -8A & I_{B} = -400mA \\ & I_{C} = -10A & I_{B} = -500mA \end{split}$ | | -0.7 -1 -1.2 | -0.15 -0.35 -0.7 | V V V V |
| V _{BE(sat)} (2) | Base-emitter saturation voltage | $I_C = -2A$ $I_B = -50mA$ $I_C = -6A$ $I_B = -250mA$ | | -1.2 | -1.1 | V V |
| h _{FE} ⁽²⁾ | DC current gain | $\begin{split} & I_{C} = -10 \text{mA} & V_{CE} = -1 V \\ & I_{C} = -500 \text{mA} & V_{CE} = -1 V \\ & I_{C} = -5 A & V_{CE} = -1 V \\ & I_{C} = -5 A & V_{CE} = -1 V \\ & T_{C} = 100 ^{\circ} C \\ & I_{C} = -8 A & V_{CE} = -1 V \\ & I_{C} = -10 A & V_{CE} = -1 V \\ \end{split}$ | 120 100 70 | 200 200 100 100 55 35 | 300 | |
| t _d t _r t _s | Resistive load Delay time Rise time Storage time Fall time | $I_{C} = -3A$ $V_{CC} = -20V$ $I_{B1} = -I_{B2} = -60 \text{mA}$ (see figure 7) | | 180 160 250 80 | 220 210 300 100 | ns ns ns |

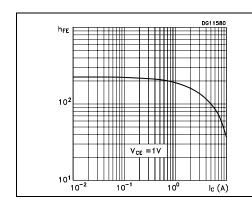
Note (2) Pulsed duration = 300 μ s, duty cycle \leq 1.5%

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2.1 Electrical characteristics (curves)

Figure 1. DC current gain

Figure 2. DC current gain



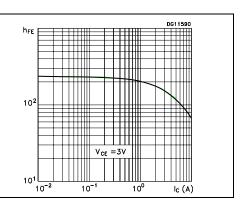
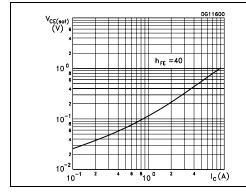


Figure 3. Collector-emitter saturation voltage

Figure 4. Base-emitter saturation voltage



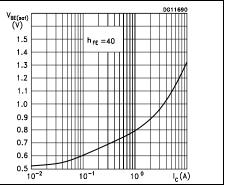
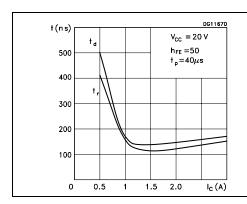
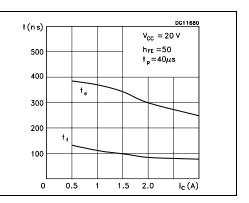


Figure 5. Switching time resistive load Figure 6. Switching time resistive load

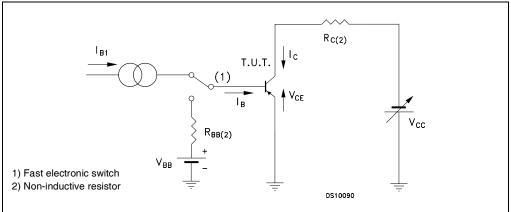




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2.2 Test circuits

Figure 7. Resistive load switching test circuit

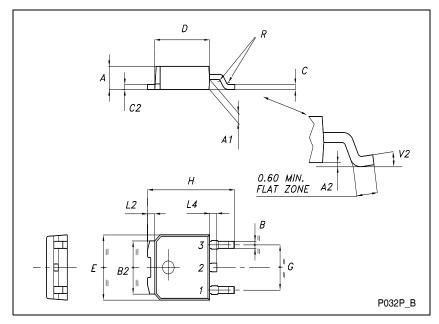


3 Package mechanical data

In order to meet environmental requirements, ST offers these devices in ECOPACK® packages. These packages have a Lead-free second level interconnect. The category of second level interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an ST trademark. ECOPACK specifications are available at: www.st.com

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| DIM. | mm | | | inch | | | |
|-------|------|------|-------|-------|-------|-------|--|
| DIWI. | MIN. | TYP. | MAX. | MIN. | TYP. | MAX. | |
| Α | 2.20 | | 2.40 | 0.087 | | 0.094 | |
| A1 | 0.90 | | 1.10 | 0.035 | | 0.043 | |
| A2 | 0.03 | | 0.23 | 0.001 | | 0.009 | |
| В | 0.64 | | 0.90 | 0.025 | | 0.035 | |
| B2 | 5.20 | | 5.40 | 0.204 | | 0.213 | |
| С | 0.45 | | 0.60 | 0.018 | | 0.024 | |
| C2 | 0.48 | | 0.60 | 0.019 | | 0.024 | |
| D | 6.00 | | 6.20 | 0.236 | | 0.244 | |
| Е | 6.40 | | 6.60 | 0.252 | | 0.260 | |
| G | 4.40 | | 4.60 | 0.173 | | 0.181 | |
| Н | 9.35 | | 10.10 | 0.368 | | 0.398 | |
| L2 | | 0.8 | | | 0.031 | | |
| L4 | 0.60 | | 1.00 | 0.024 | | 0.039 | |
| V2 | 0° | | 8° | 0° | | 0° | |



STD888T4 Revision history

4 Revision history

Table 4. Revision history

| Date | Revision | Changes | |
|-------------|----------|------------------|--|
| 24-Mar-2004 | 1 | Initial release. | |
| 03-Apr-2006 | 2 | New template. | |

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